

ASSP For Video Applications

CMOS

8-bit 140 MSPS A/D Converter

MB40C318

■ DESCRIPTION

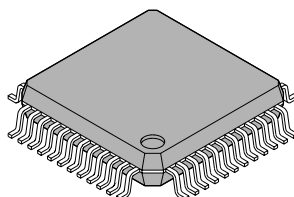
MB40C318 is a high-speed A/D converter using a fast CMOS technology.

■ FEATURES

- Resolution : 8 bit
- Linearity error : $\pm 0.40\%$ (standard)
- Maximum conversion rate : 140 MSPS (minimum)
- Power supply voltage : 3.3 V/5 V (standard: PECL clock input)
3.3 V (standard: PECL other than clock input)
- Clock input voltage range : PECL level (140 MHz max differential input CLKEP, CLKEN)
CMOS level (70 MHz max two-phase input CLKA, CLKB)
- Digital input voltage range : CMOS level
- Digital output voltage range : CMOS level compatible
- Analog input voltage range : 0 to 3.0 V (2 Vp-p)
- Analog input capacitance : 22 pF (standard)
- Power dissipation : 300 mW (standard)
- Additional features : Reference voltage generator circuit: $V_{REFT} = 3.0\text{ V}$, $V_{REFB} = 1.0\text{ V}$
High impedance output, power down function
1:2 demultiplex output enable (RESET action enable)
1/2 deviding clock output
Cross sampling at 70 MHz (two-phase CLK) enable (CLKA, CLKB)
- Package : LQFP48 (7 mm \times 7 mm, lead pitch 0.5 mm)

■ PACKAGE

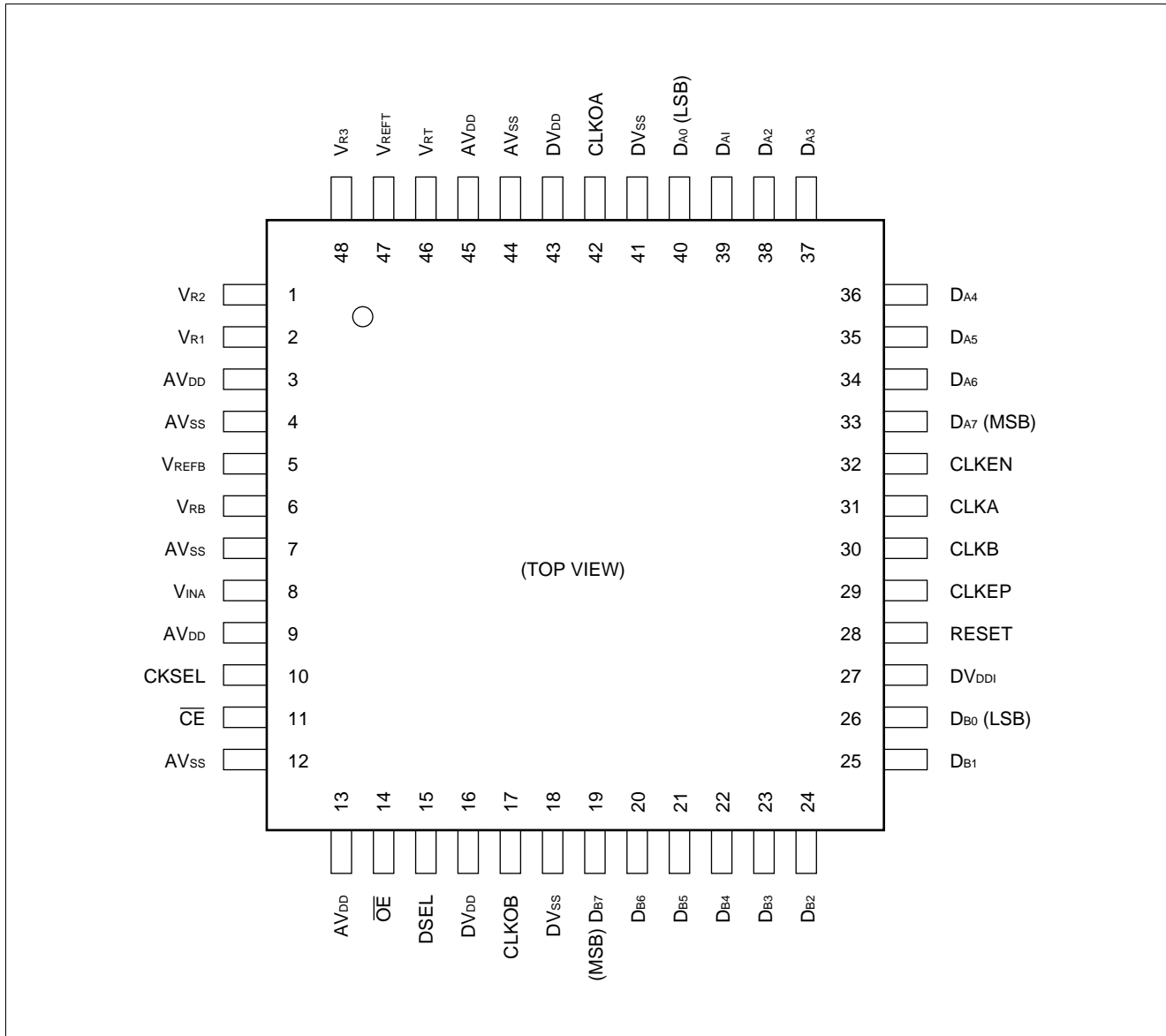
48-pin plastic LQFP



(FPT-48P-M05)

MB40C318

■ PIN ASSIGNMENT



■ PIN DESCRIPTION

Pin No.	Symbol	Description
3, 9, 13, 45	AV _{DD}	Analog power supply (+3.3 V)
16, 43	DV _{DD}	Digital power supply (+3.3 V)
27	DV _{DDI}	Digital power supply for CLKEP/CLKEN (+5.0 V or +3.3 V)
4, 7, 12, 44	AV _{SS}	Analog power supply ground pin (0 V)
18, 41	DV _{SS}	Digital power supply ground pin (0 V)
33 to 40	DA ₇ to DA ₀	Digital output pin (Port A) DA ₇ : MSB, DA ₀ : LSB
19 to 26	DB ₇ to DB ₀	Digital output pin (Port B) DB ₇ : MSB, DB ₀ : LSB
11	$\overline{\text{CE}}$	Power down at $\overline{\text{CE}}$ input "H" (internal pull-up resistor)
14	$\overline{\text{OE}}$	Digital output (Both Port A, B) and clock output (CLKOA, CLKOB) are high impedance at $\overline{\text{OE}}$ input "H".
10	CKSEL	Mode of operation setting input pin (Refer to ■ MODE SETTING)
15	DSEL	
28	RESET	Dividing circuit reset input pin (See ■ TIMING CHART 2, 3)
29	CLKEP	Differential clock (positive-phase) input pin (max 140 MHz)
32	CLKEN	Differential clock (negative-phase) input pin (max 140 MHz)
31	CLKA	Two-phase clock (A ch) input pin (max 70 MHz)
30	CLKB	Two-phase clock (B ch) input pin (max 70 MHz)
42	CLKOA	Clock output pin (See ■ TIMING CHART 1 to 4)
17	CLKOB	Clock output pin (See ■ TIMING CHART 1 to 4)
8	V _{INA}	Analog input pin Input range is V _{RT} to V _{RB} (0 V to 3.0 V: 2 V _{p-p})
2	V _{R1}	Reference 1/4 voltage output pin (Add 0.1 μF for AV _{SS})
1	V _{R2}	Reference 1/2 voltage output pin (Add 0.1 μF for AV _{SS})
48	V _{R3}	Reference 3/4 voltage output pin (Add 0.1 μF for AV _{SS})
46	V _{RT}	Reference voltage input pin on top side
47	V _{REFT}	Reference voltage output pin By connecting to V _{RT} , 0.9 × AV _{DD} (≒ 3 V) is generated.
6	V _{RB}	Reference voltage input pin on bottom side
5	V _{REFFB}	Reference voltage output pin By connecting to V _{RB} , 0.3 × AV _{DD} (≒ 1 V) is generated.

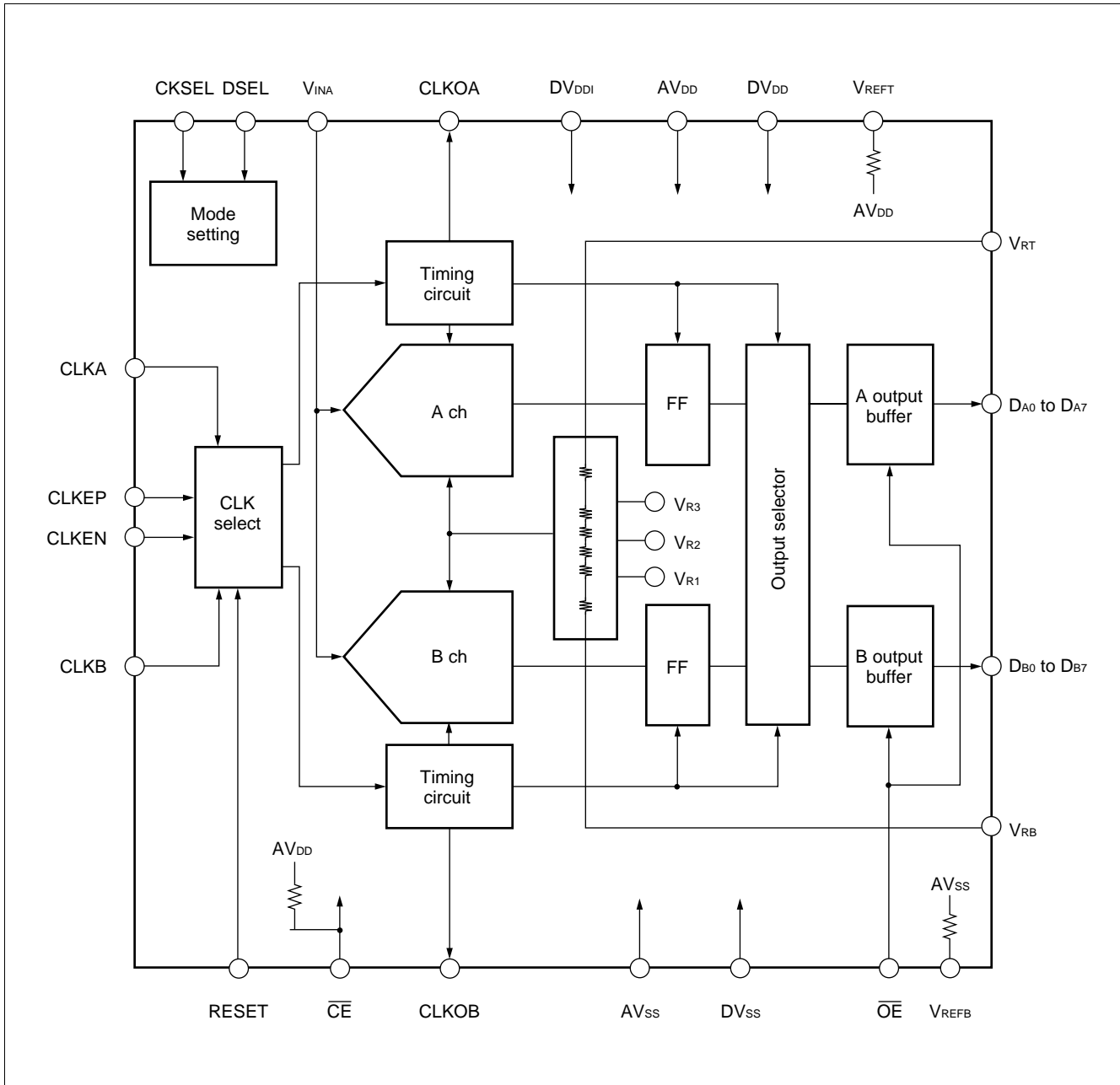
The values in parentheses are standard.

■ PRECAUTIONS ON USE

- Be sure to ground the pins of AV_{DD}, DV_{DD}, DV_{DDI}, V_{RT}, V_{RB}, V_{R1}, V_{R2}, and V_{R3} via high-frequency capacitor. Place the high-frequency capacitor as close as possible to the pin.
- To avoid generation of undesired current owing to indetermination of internal logic, set $\overline{\text{CE}}$ to "H" at powering on and input more than five clock pulses just after operation ($\overline{\text{CE}}$: "H" → "L").

MB40C318

■ BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Rating		Unit
		Min.	Max.	
Power supply voltage	AV _{DD} , DV _{DD}	-0.3	+4.0	V
	DV _{DDI}	-0.3	+7.0	V
Input/output voltage	V _{INA} , V _{RT} , V _{RB} , V _{REFT} , V _{REFB} , V _{R1} , V _{R2} , V _{R3} , $\overline{\text{CE}}$, CKSEL	-0.3	AV _{DD} +0.3*1	V
	DA ₀ to DA ₇ , DB ₀ to DB ₇ , CLKOA, CLKOB, CLKA, CLKB, DSEL, $\overline{\text{OE}}$, RESET	-0.3	DV _{DD} +0.3*1	V
	CLKEP, CLKEN	-0.3	DV _{DDI} +0.3*2	V
Storage temperature	T _{STG}	-55	+125	°C

*1: Do not exceed +4.0 V.

*2: Do not exceed +7.0 V.

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

MB40C318

■ RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Value			Unit	
		Min.	Typ.	Max.		
Power supply voltage	AV_{DD}, DV_{DD}	3.00	3.30	3.60	V	
	$DV_{DDI} (5\text{ V})$	4.75	5.00	5.25	V	
	$DV_{DDI} (3\text{ V})$	3.00	3.30	3.60	V	
Analog input voltage	V_{INA}	V_{RB}	—	V_{RT}	V	
Analog reference voltage: T	V_{RT}	—	—	3.00	V	
Analog reference voltage: B	V_{RB}	0.00	—	—	V	
Analog reference voltage range	$V_{RT} - V_{RB}$	1.90	2.00	2.10	V	
Digital “H” level input voltage	CKSEL, \overline{CE}	$AV_{DD} - 0.5$	—	—	V	
	\overline{OE} , DSEL, RESET, CLKA, CLKB	$DV_{DD} - 0.5$	—	—	V	
	CLKEP, CLKEN ($DV_{DDI} = 5\text{ V}$)	$DV_{DDI} - 1.1$	—	$DV_{DDI} - 0.6$	V	
	CLKEP, CLKEN ($DV_{DDI} = 3.3\text{ V}$)	$DV_{DDI} - 0.5$	—	DV_{DDI}	V	
Digital “L” level input voltage	CKSEL, \overline{CE}	—	—	0.5	V	
	\overline{OE} , DSEL, RESET, CLKA, CLKB	—	—	0.5	V	
	CLKEP, CLKEN ($DV_{DDI} = 5\text{ V}$)	$DV_{DDI} - 2.0$	—	$DV_{DDI} - 1.45$	V	
	CLKEP, CLKEN ($DV_{DDI} = 3.3\text{ V}$)	2.3	—	$DV_{DDI} - 0.5$	V	
Digital input voltage range	CLKEP, CLKEN ($DV_{DDI} = 5\text{ V}$)	$V_{IHD} - V_{ILD}$	0.4	0.8	—	V
	CLKEP, CLKEN ($DV_{DDI} = 3.3\text{ V}$)	$V_{IHD} - V_{ILD}$	0.4	0.6	—	V
Digital input current	I_{ID}	−20	—	5	μA	
Differential clock frequency	f_{CLKEP}, f_{CLKEN}	0.1	—	140	MHz	
Two-phase clock frequency	f_{CLKA}, f_{CLKB}	0.1	—	70	MHz	
Minimum clock pulse width (differential)	t_{WS}^+, t_{WS}^-	3.0	3.5	—	ns	
Minimum clock pulse width (two-phase)	t_{WD}^+, t_{WD}^-	6.0	7.0	—	ns	
Clock pulse rising/falling time	t_r, t_f	—	2.0	—	ns	
RESET signal setup time	t_s	1.5	—	—	ns	
RESET signal hold time	t_h	1.5	—	—	ns	
Operating temperature range	T_a	−20	—	70	$^{\circ}\text{C}$	

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device’s electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representatives beforehand.

■ ELECTRICAL CHARACTERISTICS

• DC Characteristics in Analog Section

($AV_{DD} = DV_{DD} = 3.00\text{ V to }3.60\text{ V}$, $DV_{DDI} = 4.75\text{ V to }5.25\text{ V}$, $T_a = -20^\circ\text{C to }+70^\circ\text{C}$)

Parameter	Symbol	Value			Unit
		Min.	Typ.	Max.	
Resolution	—	—	8	—	bit
Linearity error	LE	—	± 0.40	± 0.6	%
Differential linearity error	DLE	—	± 0.20	± 0.36	%
Analog input capacity	C_{INA}	—	22	—	pF
Reference voltage: T	V_{REFT}	$0.88 \times AV_{DD}$	$0.91 \times AV_{DD}$	$0.94 \times AV_{DD}$	V
Reference voltage: B	V_{REFB}	$0.27 \times AV_{DD}$	$0.3 \times AV_{DD}$	$0.33 \times AV_{DD}$	V
Reference current	I_{RB}	-15	-10	—	mA
Analog supply current	A_{DD}	—	60.0	100	mA
Digital supply current	D_{DD}	—	30.0	45	mA
	D_{DDI}	—	1	3	mA
Standby current	I_{SB}	—	1	—	mA

• DC Characteristics in Digital Section

($AV_{DD} = DV_{DD} = 3.00\text{ V to }3.60\text{ V}$, $DV_{DDI} = 4.75\text{ V to }5.25\text{ V}$, $T_a = -20^\circ\text{C to }+70^\circ\text{C}$)

Parameter	Symbol	Value			Unit
		Min.	Typ.	Max.	
Digital "H" level output voltage	V_{OHD}	$DV_{DD} - 0.4$	—	DV_{DD}	V
Digital "L" level output voltage	V_{OLD}	—	—	0.4	V
Digital "H" level output current	I_{OHD}	-400	—	—	μA
Digital "L" level output current	I_{OLD}	—	—	1.6	mA

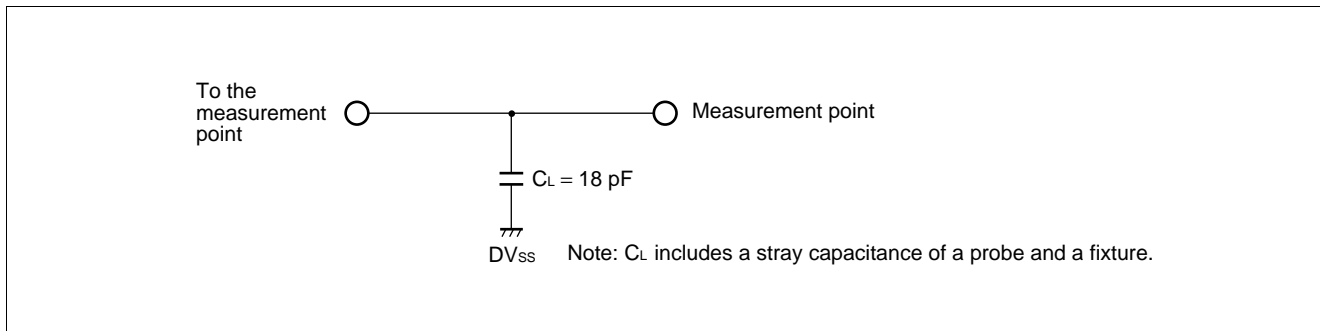
MB40C318

• Switching Characteristics

($AV_{DD} = DV_{DD} = 3.00\text{ V to }3.60\text{ V}$, $DV_{DD1} = 4.75\text{ V to }5.25\text{ V}$, $T_a = -20^\circ\text{C to }+70^\circ\text{C}$)

Parameter		Symbol	Value			Unit
			Min.	Typ.	Max.	
Maximum conversion rate		f_s	140	—	—	MSPS
Aperture time	Timing chart 1 to 3	t_{AD}	—	3.5	—	ns
	Timing chart 4		—	2.0	—	ns
Digital output delay time	Timing chart 1	t_{pdS}	4	8	11.5	ns
		t_{pdSO}	$t_{ws}^+ + 4$	$t_{ws}^+ + 8$	$t_{ws}^+ + 11$	ns
	Timing chart 2	t_{pdM1}	4	7	11.5	ns
		t_{pdM1O}	$T + 4$	$T + 7$	$T + 11$	ns
	Timing chart 3	t_{pdM2}	4	7	11.5	ns
		t_{pdM2O}	$T + 4$	$T + 7$	$T + 11$	ns
	Timing chart 4	t_{pdD}	3	6	10.5	ns
		t_{pdDO}	$t_{wD}^+ + 2$	$t_{wD}^+ + 6$	$t_{wD}^+ + 10$	ns

■ DIGITAL OUTPUT BUFFER LOAD CIRCUIT



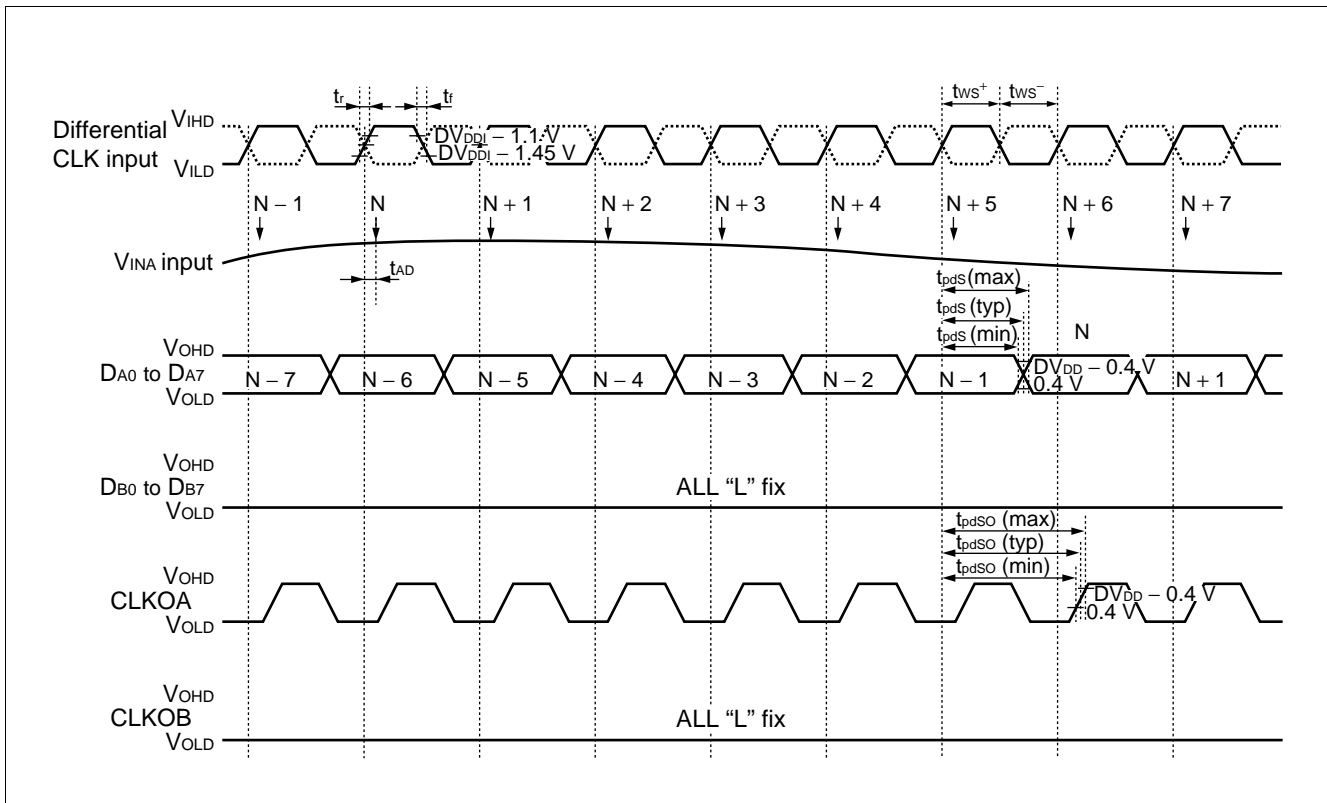
■ MODE SETTING

CKCEL	DCEL	Mode	Timing Chart
H	H	Differential CLK input-straight output mode	Timing chart 1
H	L	Differential CLK input-demultiplex output (in-phase) mode	Timing chart 2
L	H	Differential CLK input-demultiplex output (two-phase) mode	Timing chart 3
L	L	Two-phase CLK input mode (CLKA, CLKB)	Timing chart 4

■ TIMING CHART 1

Differential CLK input-straight output mode

- CLKEP = CLKEN = 140 MHz (max)
- CLKA = CLKB = "L" (DV_{SS})
- CKSEL = "H" (AV_{DD})
- DSEL = "H" (DV_{DD})
- RESET = "H" (DV_{DD})
- \overline{CE} = "L" (AV_{SS})
- \overline{OE} = "L" (DV_{SS})



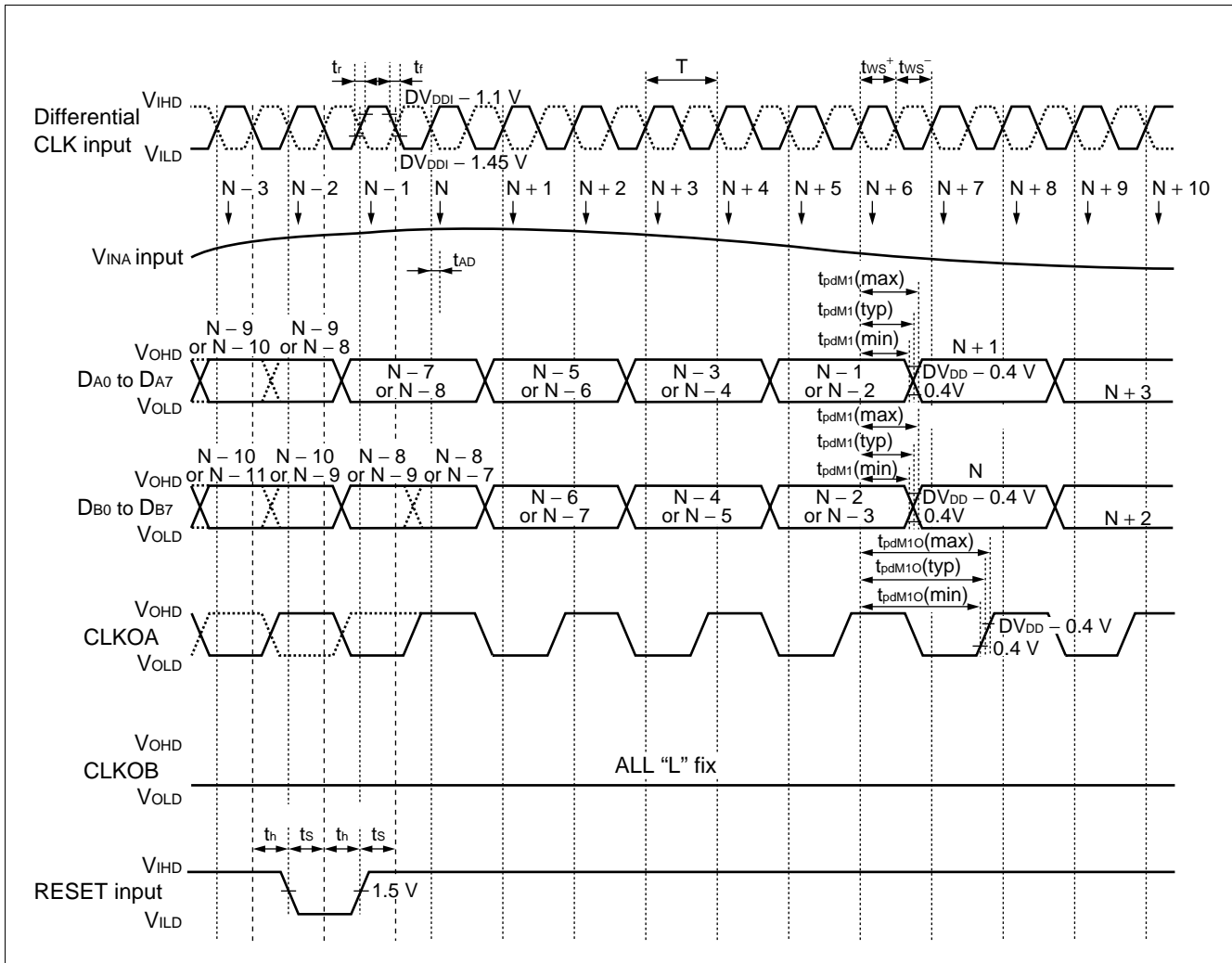
- Differential CLK input — Solid line: CLKEP, Dotted line: CLKEN
- V_{INA} input — Sampling at CLKEP rising (CLKEN falling)
- DA₀ to DA₇ — Output (after 5 CLK + t_{ps} from Sampling) at CLKEP rising (CLKEN falling)

MB40C318

■ TIMING CHART 2

Differential CLK input-demultiplex output (in-phase) mode

- CLKEP = CLKEN = 140 MHz (max)
- CLKA = CLKB = "L" (DV_{SS})
- CKSEL = "H" (AV_{DD})
- DSEL = "L" (DV_{SS})
- \overline{CE} = "L" (AV_{SS})
- \overline{OE} = "L" (DV_{SS})

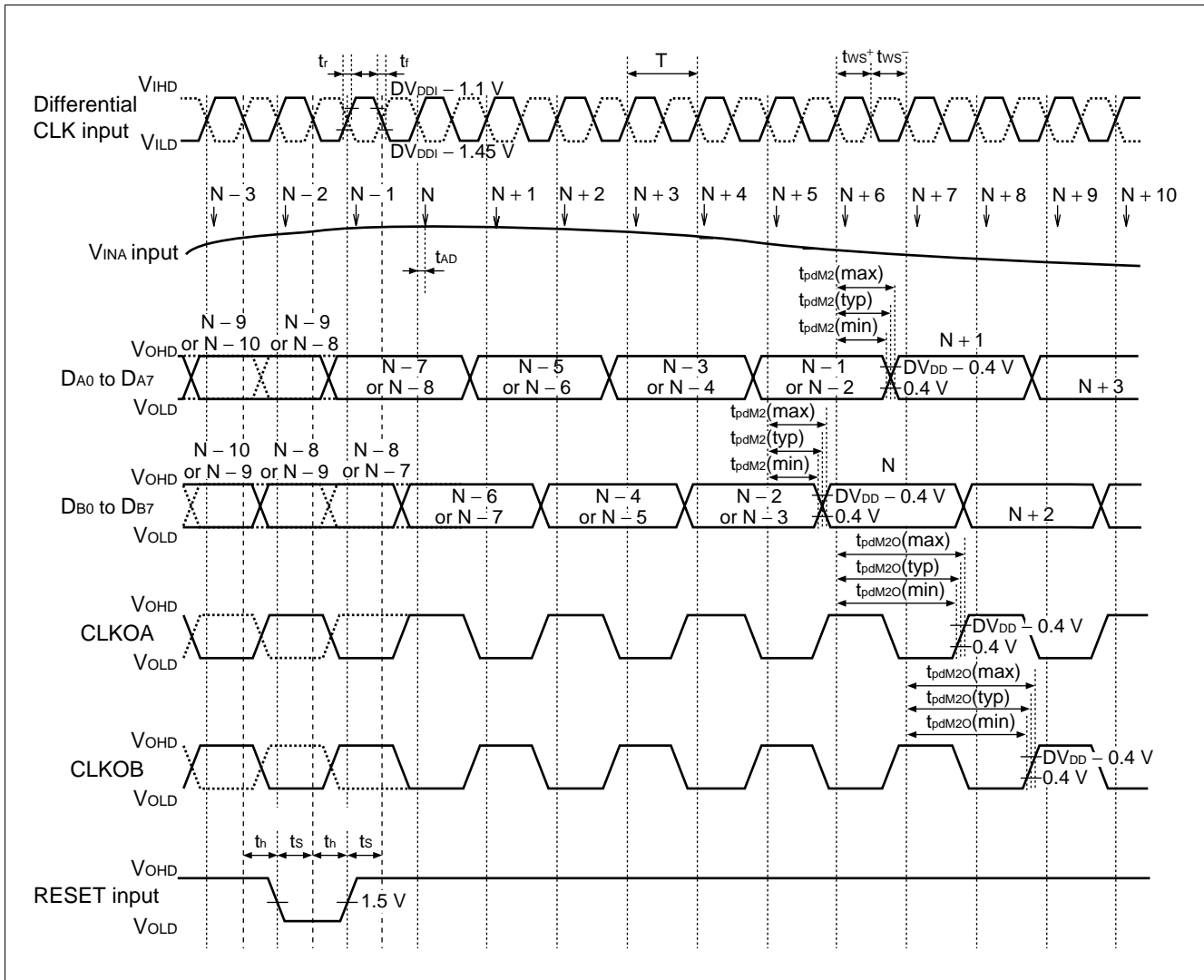


- Differential CLK input — Solid line: CLKEP, Dotted line: CLKEN
- V_{INA} input — Sampling at CLKEP rising (CLKEN falling)
- DA₀ to DA₇ — Output (after 5 CLK + t_{pdM1} from Sampling) at CLKEP rising (CLKEN falling)
- DB₀ to DB₇ — Output (after 6 CLK + t_{pdM1} from Sampling) at CLKEP rising (CLKEN falling)

■ TIMING CHART 3

Differential CLK input-demultiplex output (two-phase) mode

- CLKEP = CLKEN = 140 MHz (max)
- CLKA = CLKB = "L" (DV_{SS})
- CKSEL = "L" (AV_{SS})
- DSEL = "H" (DV_{DD})
- \overline{CE} = "L" (AV_{SS})
- \overline{OE} = "L" (DV_{SS})



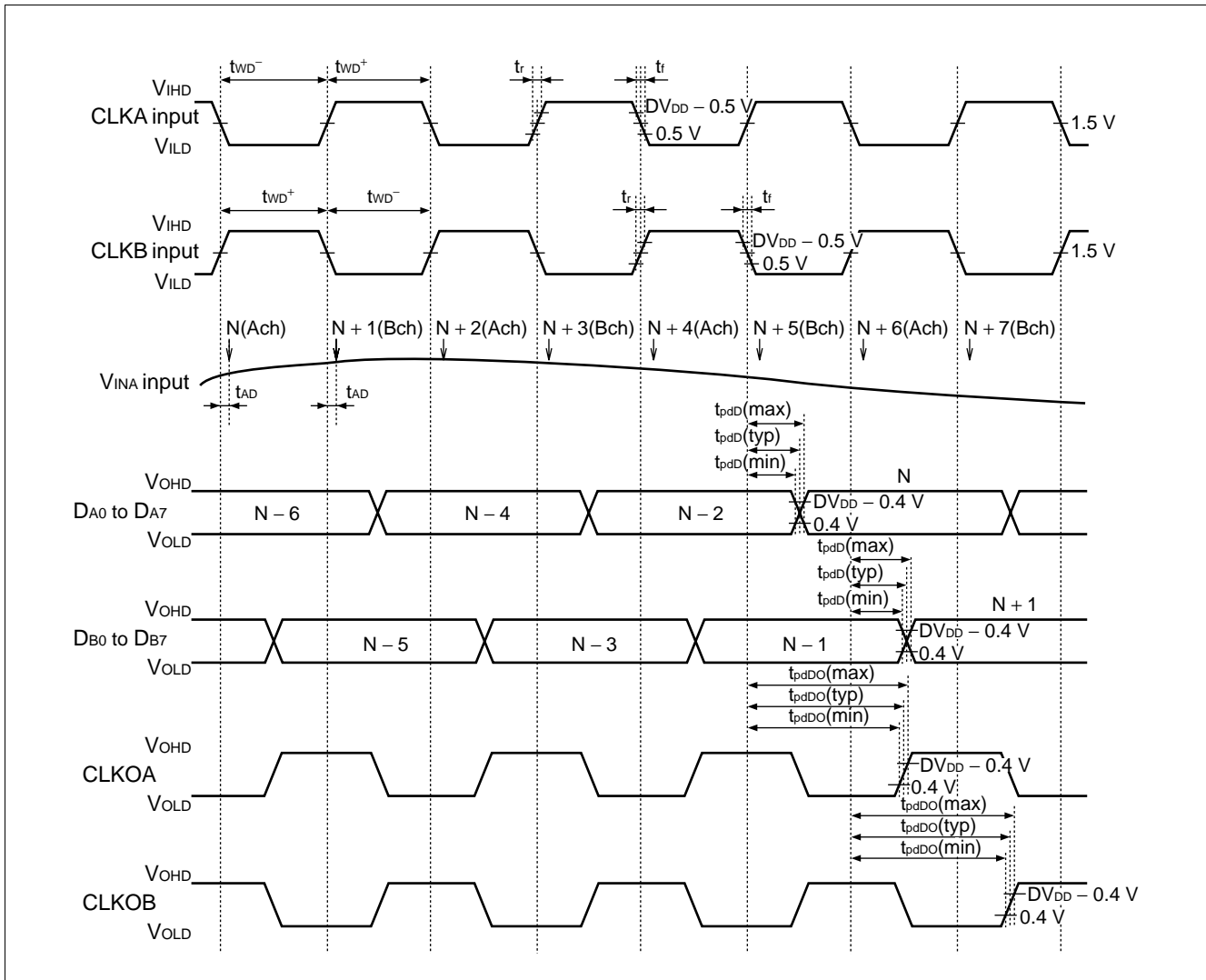
- Differential CLK input — Solid line: CLKEP, Dotted line: CLKEN
- V_{INA} input — Sampling at CLKEP rising (CLKEN falling)
- DA₀ to DA₇ — Output (after 5 CLK + t_{pdM2} from Sampling) at CLKEP rising (CLKEN falling)
- DB₀ to DB₇ — Output (after 5 CLK + t_{pdM2} from Sampling) at CLKEP rising (CLKEN falling)

MB40C318

■ TIMING CHART 4

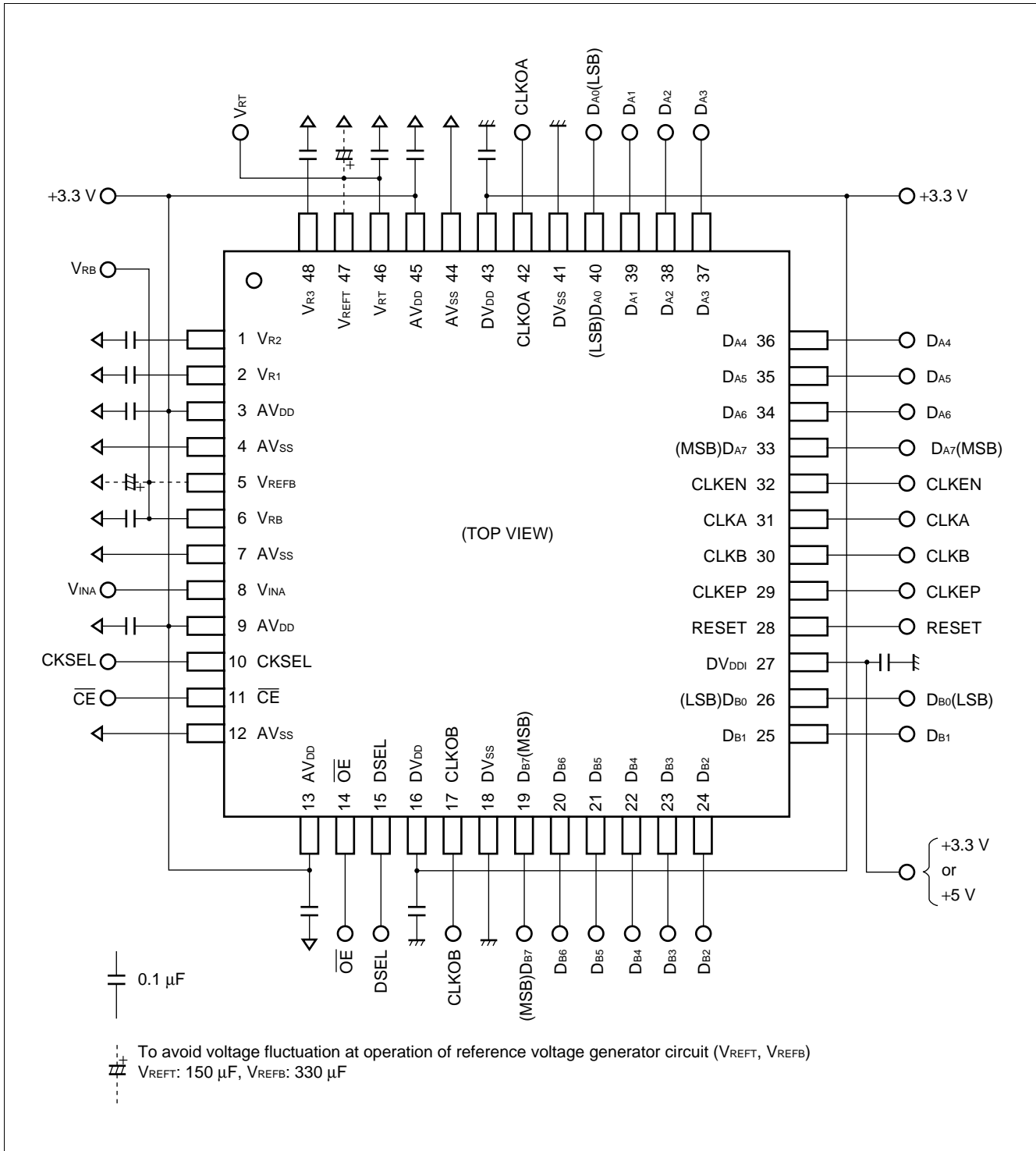
Two-phase CLK input mode (CLKA, CLKB)

- $DV_{DD1} = DV_{DD}$
- $CLKEP = "L" (DV_{SS})$, $CLKEN = "H" (DV_{DD})$ or $CLKEP = "H" (DV_{DD})$, $CLKEN = "L" (DV_{SS})$
- $CLKA = CLKB = 70 \text{ MHz (max)}$
- $CKSEL = "L" (AV_{SS})$
- $DSEL = "L" (DV_{SS})$
- $RESET = "H" (DV_{DD})$ or $RESET = "L" (DV_{SS})$
- $\overline{CE} = "L" (AV_{SS})$
- $\overline{OE} = "L" (DV_{SS})$



- V_{INA} input — Sampling (A ch) at CLKA falling
Sampling (B ch) at CLKB falling
- DA_0 to DA_7 — Output (after $2.5 \text{ CLK} + t_{pdD}$ from Sampling) at CLKA rising
- DB_0 to DB_7 — Output (after $2.5 \text{ CLK} + t_{pdD}$ from Sampling) at CLKB rising

TYPICAL CONNECTION EXAMPLE



MB40C318

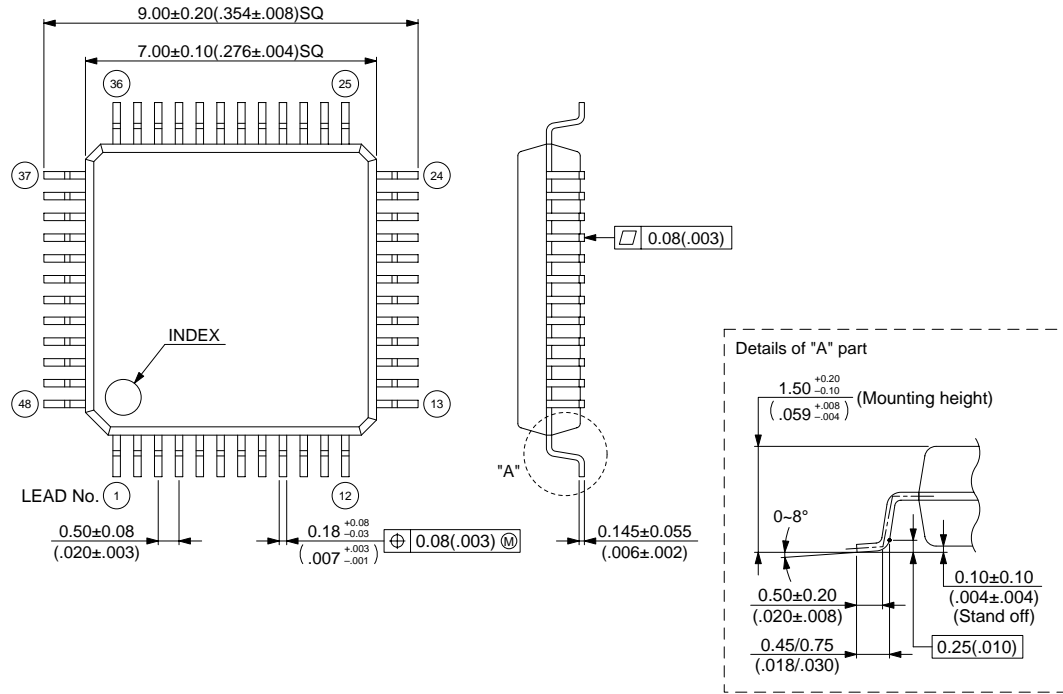
■ ORDERING INFORMATION

Part number	Package	Remark
MB40C318PFV	48-pin Plastic LQFP (FPT-48P-M05)	

■ PACKAGE DIMENSION

48-pin Plastic LQFP
(FPT-48P-M05)

Note) Pins width and pins thickness include plating thickness.



FUJITSU LIMITED

All Rights Reserved.

The contents of this document are subject to change without notice. Customers are advised to consult with FUJITSU sales representatives before ordering.

The information and circuit diagrams in this document are presented as examples of semiconductor device applications, and are not intended to be incorporated in devices for actual use. Also, FUJITSU is unable to assume responsibility for infringement of any patent rights or other rights of third parties arising from the use of this information or circuit diagrams.

The products described in this document are designed, developed and manufactured as contemplated for general use, including without limitation, ordinary industrial use, general office use, personal use, and household use, but are not designed, developed and manufactured as contemplated (1) for use accompanying fatal risks or dangers that, unless extremely high safety is secured, could have a serious effect to the public, and could lead directly to death, personal injury, severe physical damage or other loss (i.e., nuclear reaction control in nuclear facility, aircraft flight control, air traffic control, mass transport control, medical life support system, missile launch control in weapon system), or (2) for use requiring extremely high reliability (i.e., submersible repeater and artificial satellite).

Please note that Fujitsu will not be liable against you and/or any third party for any claims or damages arising in connection with above-mentioned uses of the products.

Any semiconductor devices have an inherent chance of failure. You must protect against injury, damage or loss from such failures by incorporating safety design measures into your facility and equipment such as redundancy, fire protection, and prevention of over-current levels and other abnormal operating conditions.

If any products described in this document represent goods or technologies subject to certain restrictions on export under the Foreign Exchange and Foreign Trade Law of Japan, the prior authorization by Japanese government will be required for export of those products from Japan.

F0001

© FUJITSU LIMITED Printed in Japan